

PMP5501V; PMP5501G; PMP5501Y

PNP/PNP matched double transistors

Rev. 02 — 19 September 2006

Product data sheet

1. Product profile

1.1 General description

PNP/PNP matched double transistors in small Surface-Mounted Device (SMD) plastic packages. The transistors in the SOT666 and SOT363 (SC-88) packages are fully isolated internally.

Table 1. Product overview

| Type number | Package | | PNP/PNP h_{FE1}/h_{FE2} 0.98 complement | NPN/NPN complement |
|-------------|---------|--------|--|-----------------------|
| | Philips | JEITA | | |
| PMP5501V | SOT666 | - | PMP5201V | PMP4501V |
| PMP5501G | SOT353 | SC-88A | PMP5201G | PMP4501G |
| PMP5501Y | SOT363 | SC-88 | PMP5201Y | PMP4501Y |

1.2 Features

- Current gain matching
- Base-emitter voltage matching
- Common emitter configuration for SOT353 types
- Application-optimized pinout

1.3 Applications

- Current mirror
- Differential amplifier

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------|---------------------------|---|-----|-----|------|------|
| Per transistor | | | | | | |
| V_{CEO} | collector-emitter voltage | open base | - | - | -45 | V |
| I_C | collector current | | - | - | -100 | mA |
| h_{FE} | DC current gain | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | 200 | 290 | 450 | |

Table 2. Quick reference data ...continued

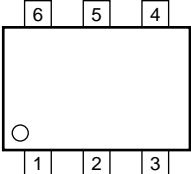
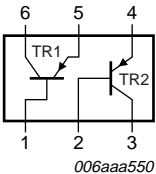
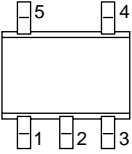
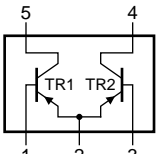
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------|-------------------|---|----------|-----|-----|------|
| Per device | | | | | | |
| h_{FE1}/h_{FE2} | h_{FE} matching | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [1] 0.95 | 1 | - | |
| $V_{BE1}-V_{BE2}$ | V_{BE} matching | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [2] - | - | 2 | mV |

[1] The smaller of the two values is taken as the numerator.

[2] The smaller of the two values is subtracted from the larger value.

2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----------------------|------------------|---|---|
| SOT666; SOT363 | | | |
| 1 | base TR1 |  |  |
| 2 | base TR2 | | |
| 3 | collector TR2 | | |
| 4 | emitter TR2 | | |
| 5 | emitter TR1 | | |
| 6 | collector TR1 | | |
| SOT353 | | | |
| 1 | base TR1 |  |  |
| 2 | emitter TR1, TR2 | | |
| 3 | base TR2 | | |
| 4 | collector TR2 | | |
| 5 | collector TR1 | | |

3. Ordering information

Table 4. Ordering information

| Type number | Package | | Version |
|-------------|---------|--|---------|
| | Name | Description | |
| PMP5501V | - | plastic surface-mounted package; 6 leads | SOT666 |
| PMP5501G | SC-88A | plastic surface-mounted package; 5 leads | SOT353 |
| PMP5501Y | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |

4. Marking

Table 5. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PMP5501V | ED |
| PMP5501G | R4* |
| PMP5501Y | S6* |

- [1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------|---------------------------|----------------------------------|---------------------|------|------|
| Per transistor | | | | | |
| V_{CBO} | collector-base voltage | open emitter | - | -50 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -45 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I_C | collector current | | - | -100 | mA |
| I_{CM} | peak collector current | single pulse; $t_p \leq 1$ ms | - | -200 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | | | |
| | SOT666 | | ^{[1][2]} - | 200 | mW |
| | SOT353 | | ^[1] - | 200 | mW |
| | SOT363 | | ^[1] - | 200 | mW |
| Per device | | | | | |
| P_{tot} | total power dissipation | $T_{amb} \leq 25$ °C | | | |
| | SOT666 | | ^{[1][2]} - | 300 | mW |
| | SOT353 | | ^[1] - | 300 | mW |
| | SOT363 | | ^[1] - | 300 | mW |
| T_j | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | -65 | +150 | °C |
| T_{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-----------------------|---|-------------|--------|-----|-----|------|-----|
| Per transistor | | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | | | | | |
| | SOT666 | | [1][2] | - | - | 625 | K/W |
| | SOT353 | | [1] | - | - | 625 | K/W |
| | SOT363 | | [1] | - | - | 625 | K/W |
| Per device | | | | | | | |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | | | | | |
| | SOT666 | | [1][2] | - | - | 416 | K/W |
| | SOT353 | | [1] | - | - | 416 | K/W |
| | SOT363 | | [1] | - | - | 416 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

7. Characteristics

Table 8. Characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------|--------------------------------------|--|-----|------|------|---------------|
| Per transistor | | | | | | |
| I_{CBO} | collector-base cut-off current | $V_{CB} = -30\text{ V};$ $I_E = 0\text{ A}$ | - | - | -15 | nA |
| | | $V_{CB} = -30\text{ V};$ $I_E = 0\text{ A};$ $T_j = 150\text{ °C}$ | - | - | -5 | μA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = -5\text{ V};$ $I_C = 0\text{ A}$ | - | - | -100 | nA |
| h_{FE} | DC current gain | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ }\mu\text{A}$ | - | 250 | - | |
| | | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | 200 | 290 | 450 | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = -10\text{ mA};$ $I_B = -0.5\text{ mA}$ | - | -50 | -200 | mV |
| | | $I_C = -100\text{ mA};$ $I_B = -5\text{ mA}$ | - | -200 | -400 | mV |
| V_{BEsat} | base-emitter saturation voltage | $I_C = -10\text{ mA};$ $I_B = -0.5\text{ mA}$ | [1] | - | -760 | mV |
| | | $I_C = -100\text{ mA};$ $I_B = -5\text{ mA}$ | [1] | - | -920 | mV |

Table 8. Characteristics ...continued $T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------|-----------------------|---|----------|------|------|------|
| V_{BE} | base-emitter voltage | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [2] -600 | -650 | -700 | mV |
| | | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ mA}$ | [2] - | - | -760 | mV |
| C_c | collector capacitance | $V_{CB} = -10\text{ V};$ $I_E = i_e = 0\text{ A};$ $f = 1\text{ MHz}$ | - | - | 2.2 | pF |
| C_e | emitter capacitance | $V_{EB} = -0.5\text{ V};$ $I_C = i_c = 0\text{ A};$ $f = 1\text{ MHz}$ | - | 10 | - | pF |
| f_T | transition frequency | $V_{CE} = -5\text{ V};$ $I_C = -10\text{ mA};$ $f = 100\text{ MHz}$ | 100 | 175 | - | MHz |
| NF | noise figure | $V_{CE} = -5\text{ V};$ $I_C = -0.2\text{ mA};$ $R_S = 2\text{ k}\Omega;$ $f = 10\text{ Hz to}$ 15.7 kHz | - | 1.6 | - | dB |
| | | $V_{CE} = -5\text{ V};$ $I_C = -0.2\text{ mA};$ $R_S = 2\text{ k}\Omega;$ $f = 1\text{ kHz};$ $B = 200\text{ Hz}$ | - | 3.1 | - | dB |
| Per device | | | | | | |
| h_{FE1}/h_{FE2} | h_{FE} matching | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [3] 0.95 | 1 | - | |
| $V_{BE1}-V_{BE2}$ | V_{BE} matching | $V_{CE} = -5\text{ V};$ $I_C = -2\text{ mA}$ | [4] - | - | 2 | mV |

[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

[3] The smaller of the two values is taken as the numerator.

[4] The smaller of the two values is subtracted from the larger value.

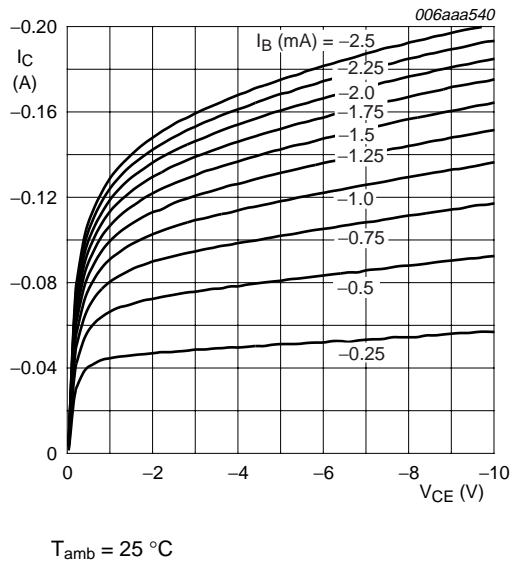


Fig 1. Collector current as a function of collector-emitter voltage; typical values

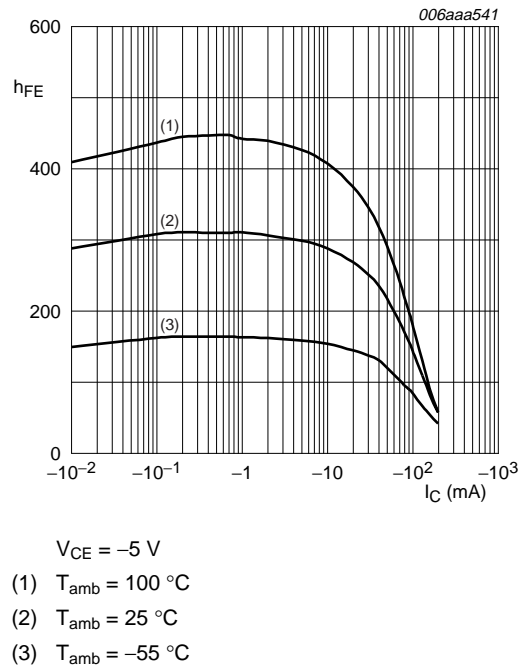


Fig 2. DC current gain as a function of collector current; typical values

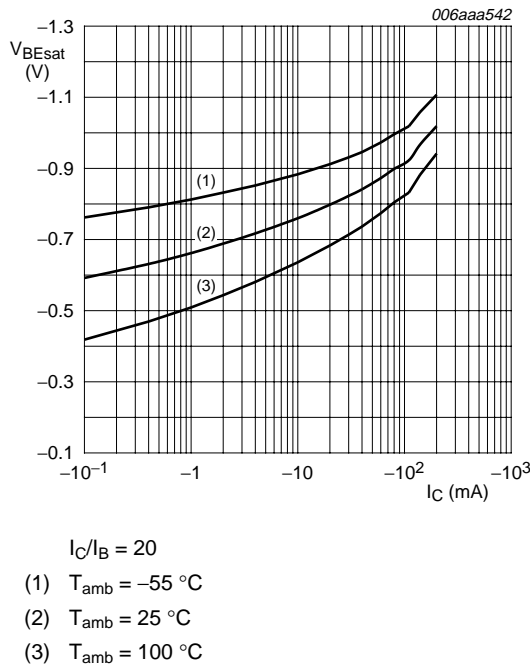


Fig 3. Base-emitter saturation voltage as a function of collector current; typical values

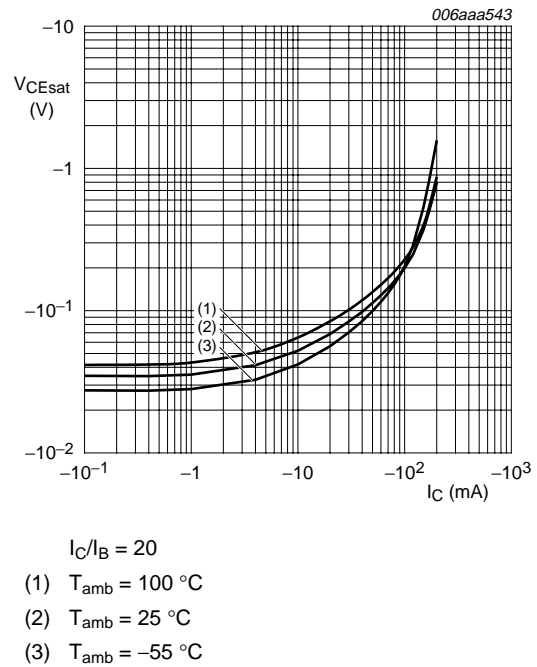
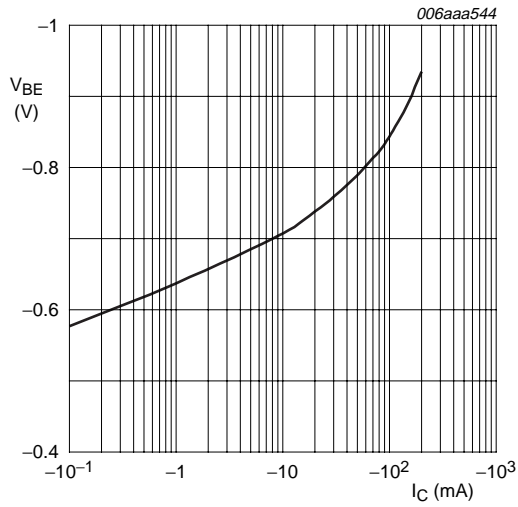
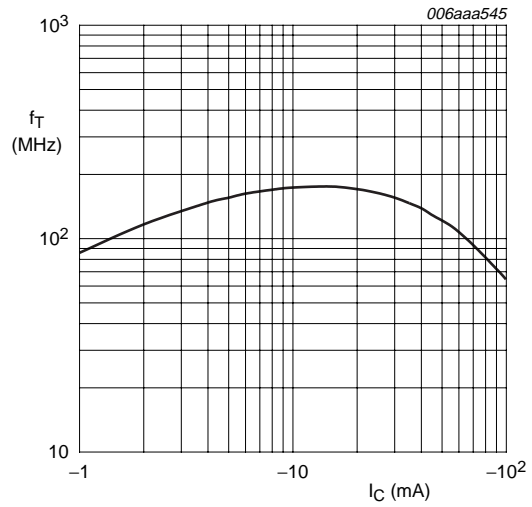


Fig 4. Collector-emitter saturation voltage as a function of collector current; typical values



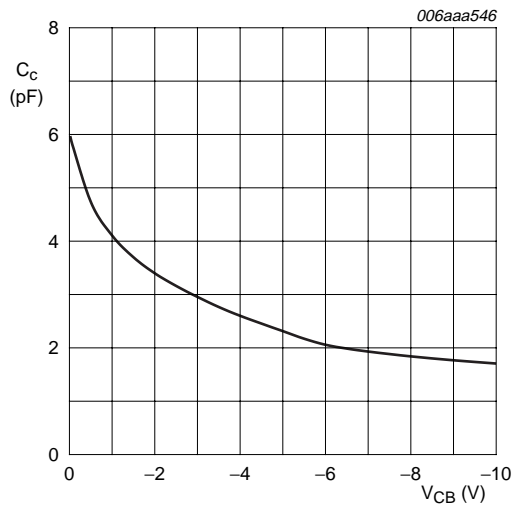
$V_{CE} = -5\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$

Fig 5. Base-emitter voltage as a function of collector current; typical values



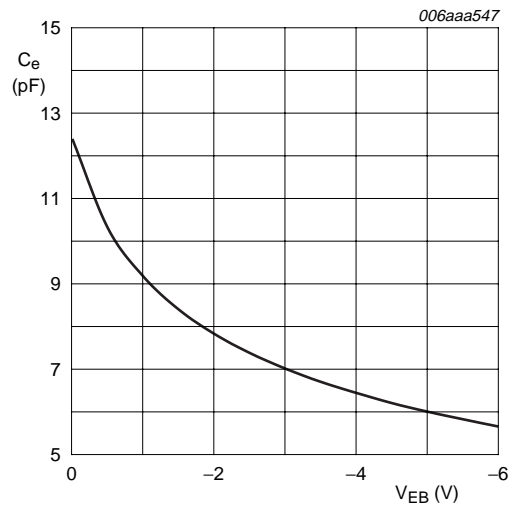
$V_{CE} = -5\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$

Fig 6. Transition frequency as a function of collector current; typical values



$f = 1\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$

Fig 7. Collector capacitance as a function of collector-base voltage; typical values



$f = 1\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$

Fig 8. Emitter capacitance as a function of emitter-base voltage; typical values

8. Application information

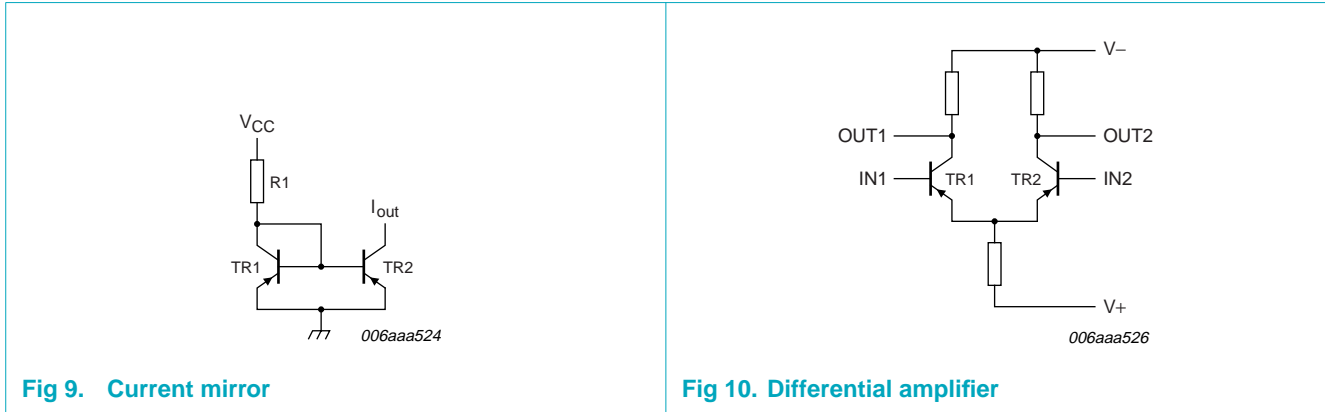


Fig 9. Current mirror

Fig 10. Differential amplifier

9. Package outline

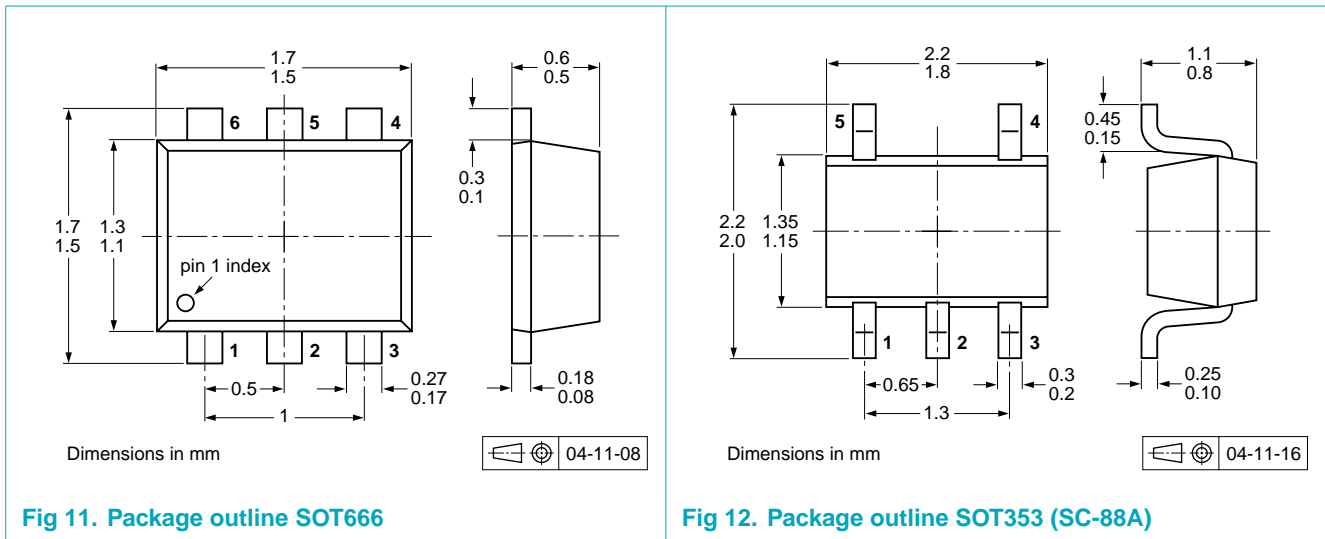


Fig 11. Package outline SOT666

Fig 12. Package outline SOT353 (SC-88A)

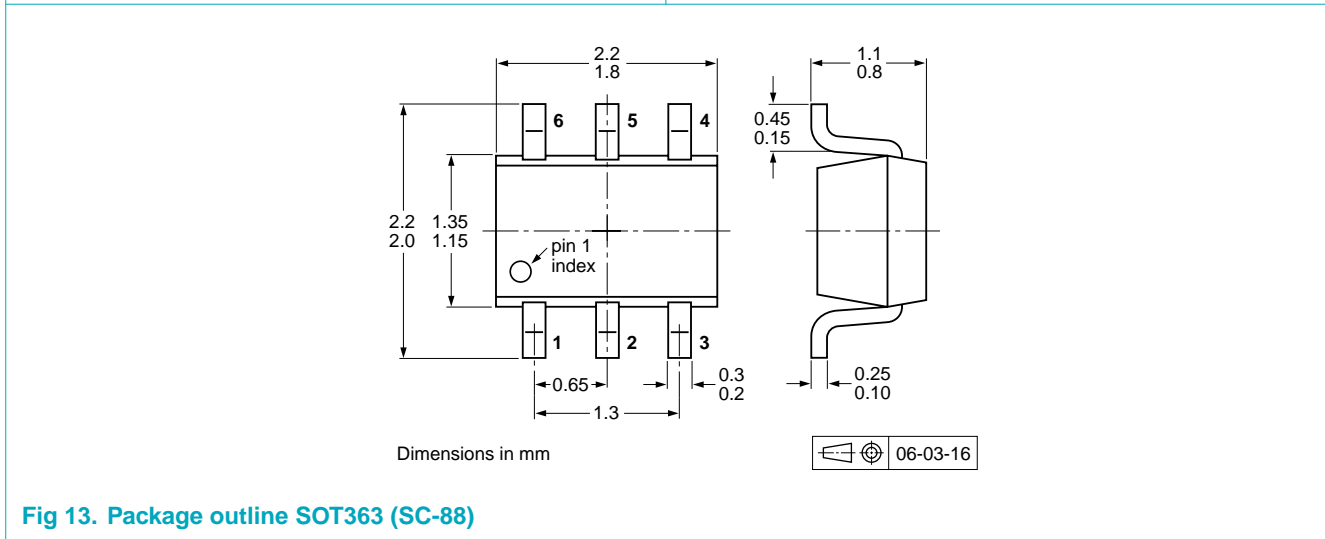


Fig 13. Package outline SOT363 (SC-88)

10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

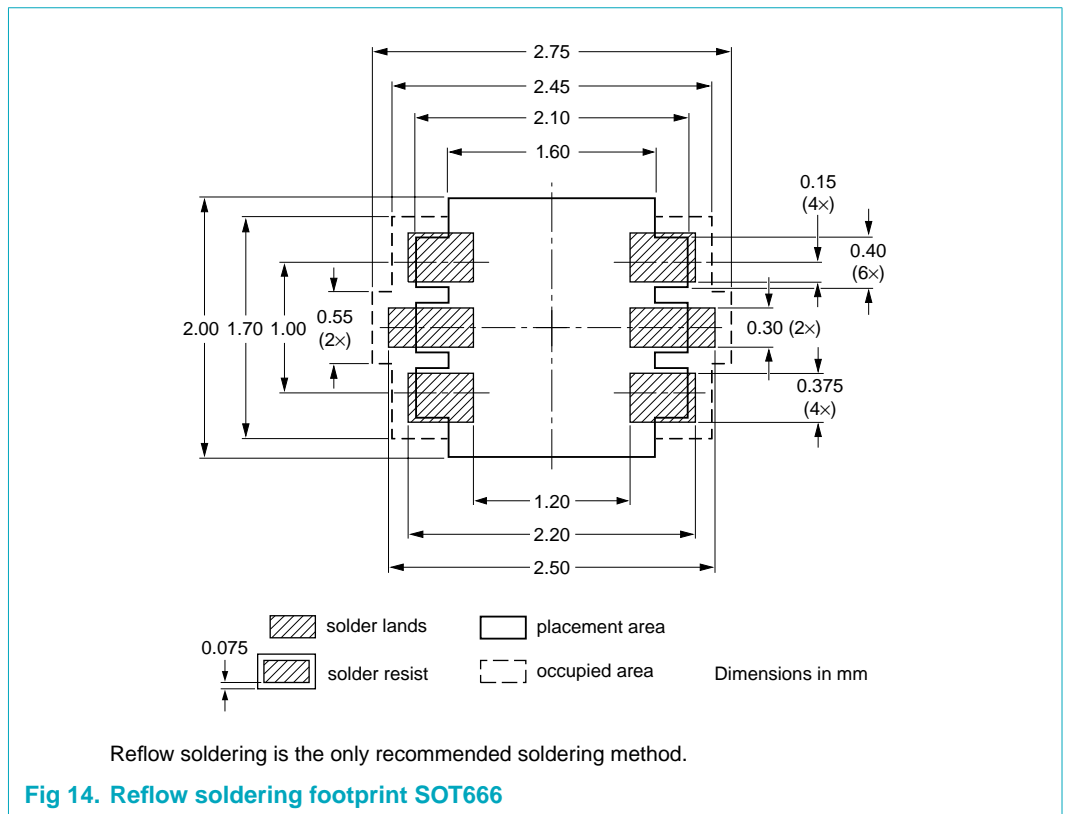
| Type number | Package | Description | Packing quantity | | | |
|-------------|---------|---|------------------|------|------|-------|
| | | | 3000 | 4000 | 8000 | 10000 |
| PMP5501V | SOT666 | 2 mm pitch, 8 mm tape and reel | - | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | - | -115 | - | - |
| PMP5501G | SOT353 | 4 mm pitch, 8 mm tape and reel | -115 | - | - | -135 |
| PMP5501Y | SOT363 | 4 mm pitch, 8 mm tape and reel; T1 ^[2] | -115 | - | - | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 ^[3] | -125 | - | - | -165 |

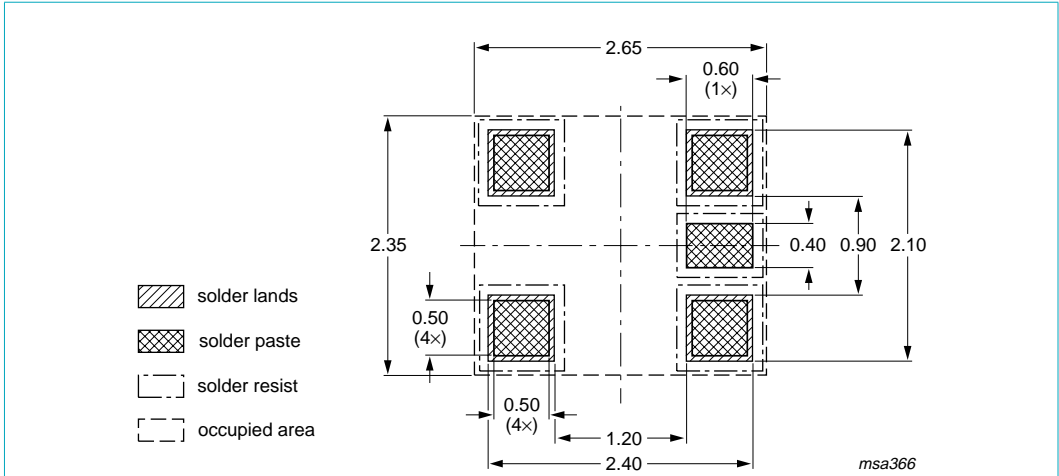
[1] For further information and the availability of packing methods, see [Section 14](#).

[2] T1: normal taping

[3] T2: reverse taping

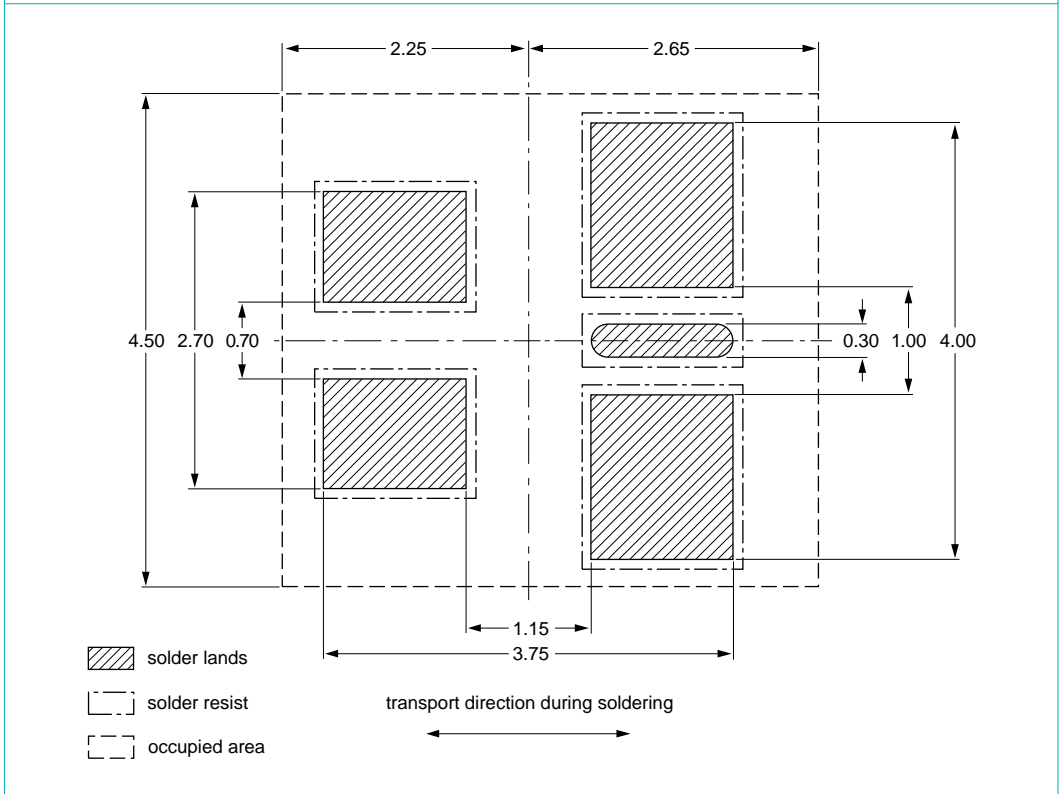
11. Soldering





Dimensions in mm

Fig 15. Reflow soldering footprint SOT353 (SC-88A)



Dimensions in mm

Fig 16. Wave soldering footprint SOT353 (SC-88A)

12. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|--------------------|---------------|--------------|
| PMP5501V_G_Y_2 | 20060919 | Product data sheet | - | PMP5501G_Y_1 |
| Modifications: | <ul style="list-style-type: none">Type number PMP5501V addedSection 13 "Legal information": updated | | | |
| PMP5501G_Y_1 | 20060221 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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15. Contents

| | | |
|-----------|--|-----------|
| 1 | Product profile | 1 |
| 1.1 | General description. | 1 |
| 1.2 | Features | 1 |
| 1.3 | Applications | 1 |
| 1.4 | Quick reference data. | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Marking | 3 |
| 5 | Limiting values | 3 |
| 6 | Thermal characteristics | 4 |
| 7 | Characteristics | 4 |
| 8 | Application information | 8 |
| 9 | Package outline | 8 |
| 10 | Packing information | 9 |
| 11 | Soldering | 9 |
| 12 | Revision history | 12 |
| 13 | Legal information | 13 |
| 13.1 | Data sheet status | 13 |
| 13.2 | Definitions. | 13 |
| 13.3 | Disclaimers | 13 |
| 13.4 | Trademarks. | 13 |
| 14 | Contact information | 13 |
| 15 | Contents | 14 |



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